

MOSFETs Silicon N-channel MOS (U-MOSIX-H)

# XPH2R404PB

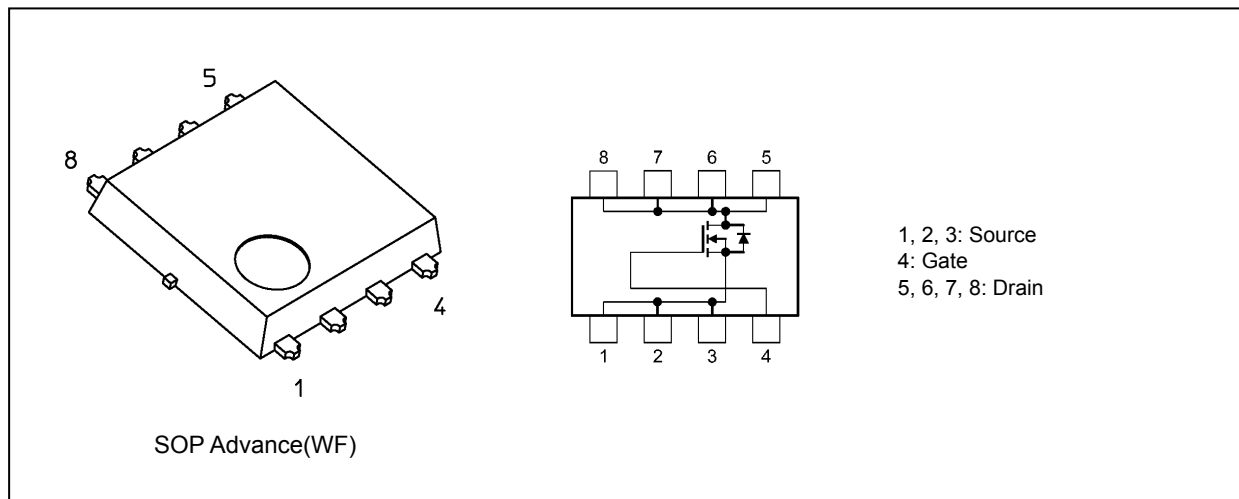
## 1. Applications

- Automotive
- Motor Drivers
- Switching Voltage Regulators

## 2. Features

- (1) AEC-Q101 qualified
- (2) Small, thin package
- (3) Low drain-source on-resistance:  $R_{DS(ON)} = 1.8 \text{ m}\Omega$  (typ.) ( $V_{GS} = 10 \text{ V}$ )
- (4) Low leakage current:  $I_{DSS} = 10 \text{ }\mu\text{A}$  (max) ( $V_{DS} = 40 \text{ V}$ )
- (5) Enhancement mode:  $V_{th} = 2.0 \text{ to } 3.0 \text{ V}$  ( $V_{DS} = 10 \text{ V}$ ,  $I_D = 0.3 \text{ mA}$ )

## 3. Packaging and Internal Circuit



Start of commercial production

2022-09

## 4. Absolute Maximum Ratings (Note) ( $T_a = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	$V_{DS}$	40	V
Gate-source voltage	$V_{GS}$	+20/-8	
Drain current (DC) (Note 1)	$I_D$	90	A
Drain current (pulsed) (Note 1)	$I_{DP}$	180	
Power dissipation ( $T_c = 25\text{ }^{\circ}\text{C}$ )	$P_D$	93	W
Power dissipation ( $t = 10\text{ s}$ ) (Note 2)		3.0	
Power dissipation ( $t = 10\text{ s}$ ) (Note 3)		0.96	
Single-pulse avalanche energy (Note 4)	$E_{AS}$	87	mJ
Single-pulse avalanche current	$I_{AS}$	45	A
Channel temperature (Note 5)	$T_{ch}$	175	$^{\circ}\text{C}$
Storage temperature (Note 5)	$T_{stg}$	-55 to 175	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

## 5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-case thermal impedance ( $T_c = 25\text{ }^{\circ}\text{C}$ )	$Z_{th(ch-c)}$	1.6	$^{\circ}\text{C/W}$
Channel-to-ambient thermal impedance ( $t = 10\text{ s}$ ) (Note 2)	$Z_{th(ch-a)}$	50	
Channel-to-ambient thermal impedance ( $t = 10\text{ s}$ ) (Note 3)	$Z_{th(ch-a)}$	156	

Note 1: Ensure that the channel temperature does not exceed  $175\text{ }^{\circ}\text{C}$ .

Note 2: Device mounted on a glass-epoxy board (a), Figure 5.1

Note 3: Device mounted on a glass-epoxy board (b), Figure 5.2

Note 4:  $V_{DD} = 32\text{ V}$ ,  $T_{ch} = 25\text{ }^{\circ}\text{C}$  (initial),  $L = 33\text{ }\mu\text{H}$ ,  $R_G = 25\text{ }\Omega$ ,  $I_{AS} = 45\text{ A}$

Note 5: The definitions of the absolute maximum channel and storage temperatures are qualified per AEC-Q101.

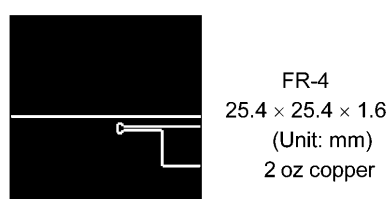


Fig. 5.1 Device Mounted on a Glass-Epoxy Board (a)

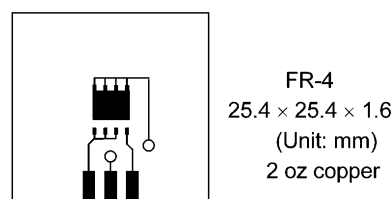


Fig. 5.2 Device Mounted on a Glass-Epoxy Board (b)

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

## 6. Electrical Characteristics

### 6.1. Static Characteristics ( $T_a = 25^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	$I_{GSS}$	$V_{GS} = +20/-8\text{ V}$ , $V_{DS} = 0\text{ V}$	—	—	$\pm 1$	$\mu\text{A}$
Drain cut-off current	$I_{DSS}$	$V_{DS} = 40\text{ V}$ , $V_{GS} = 0\text{ V}$	—	—	10	
Drain-source breakdown voltage	$V_{(BR)DSS}$	$I_D = 10\text{ mA}$ , $V_{GS} = 0\text{ V}$	40	—	—	V
	$V_{(BR)DSX}$	$I_D = 10\text{ mA}$ , $V_{GS} = -8\text{ V}$	20	—	—	
Gate threshold voltage	$V_{th}$	$V_{DS} = 10\text{ V}$ , $I_D = 0.3\text{ mA}$	2.0	—	3.0	
Drain-source on-resistance	$R_{DS(ON)}$	$V_{GS} = 6\text{ V}$ , $I_D = 45\text{ A}$	—	2.5	4.1	$\text{m}\Omega$
		$V_{GS} = 10\text{ V}$ , $I_D = 45\text{ A}$	—	1.8	2.4	

### 6.2. Dynamic Characteristics ( $T_a = 25^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Input capacitance	$C_{iss}$	$V_{DS} = 10\text{ V}$ , $V_{GS} = 0\text{ V}$ , $f = 1\text{ MHz}$	—	2500	—	$\text{pF}$
Reverse transfer capacitance	$C_{rss}$		—	190	—	
Output capacitance	$C_{oss}$		—	1600	—	
Gate resistance	$r_g$		—	2.6	5.2	$\Omega$
Switching time (rise time)	$t_r$	See Fig. 6.2.1	—	24	—	ns
Switching time (turn-on time)	$t_{on}$		—	36	—	
Switching time (fall time)	$t_f$		—	22	—	
Switching time (turn-off time)	$t_{off}$		—	79	—	

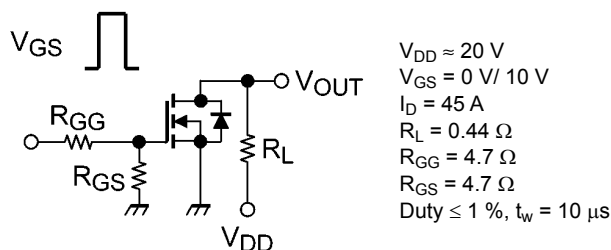


Fig. 6.2.1 Switching Time Test Circuit

### 6.3. Gate Charge Characteristics ( $T_a = 25^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Total gate charge (gate-source plus gate-drain)	$Q_g$	$V_{DD} \approx 32\text{ V}$ , $V_{GS} = 10\text{ V}$ , $I_D = 90\text{ A}$	—	40	—	nC
Gate-source charge 1	$Q_{gs1}$		—	15	—	
Gate-drain charge	$Q_{gd}$		—	7	—	

### 6.4. Source-Drain Characteristics ( $T_a = 25^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Reverse drain current (pulsed) (Note 6)	$I_{DRP}$	—	—	—	180	A
Diode forward voltage	$V_{DSF}$	$I_{DR} = 90\text{ A}$ , $V_{GS} = 0\text{ V}$	—	—	-1.2	V

Note 6: Ensure that the channel temperature does not exceed  $175^\circ\text{C}$ .

## 7. Marking

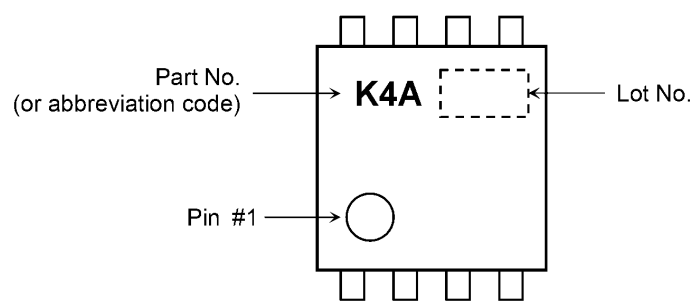
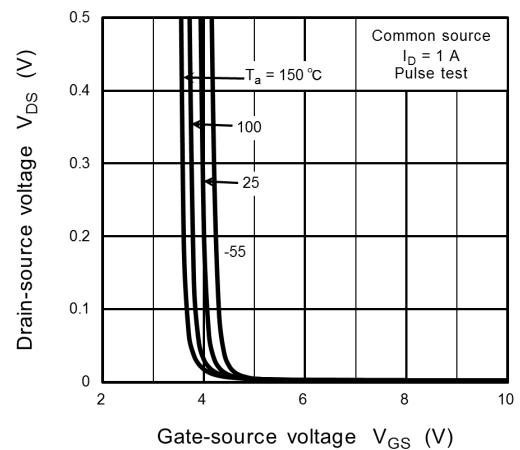
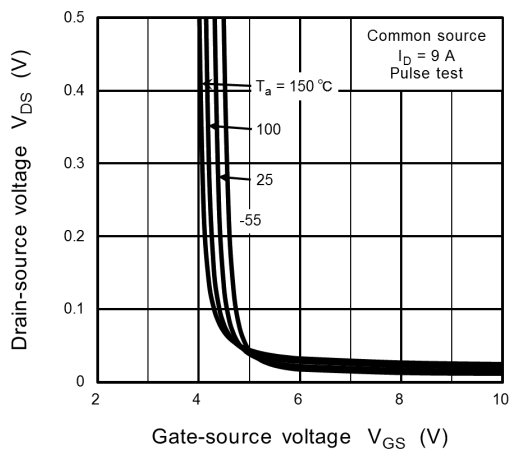
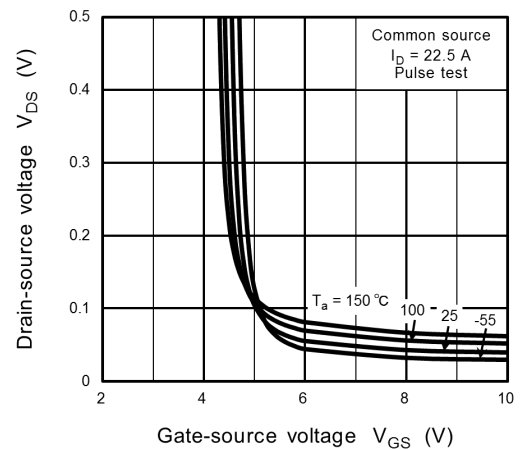
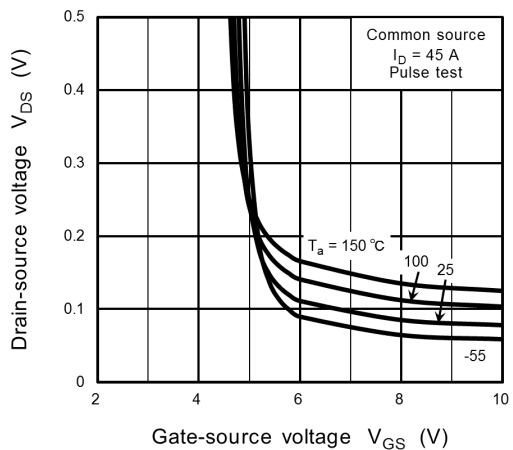
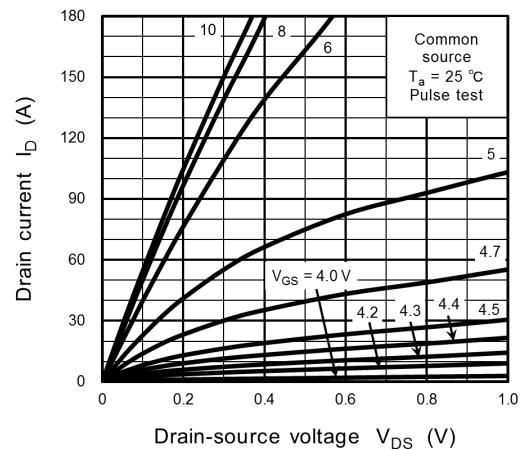
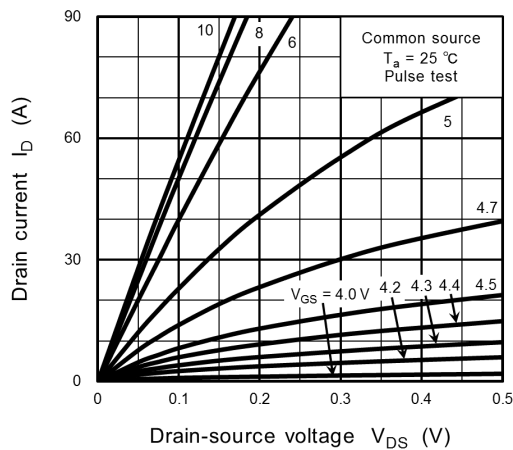


Fig. 7.1 Marking

8. Characteristics Curves (Note)



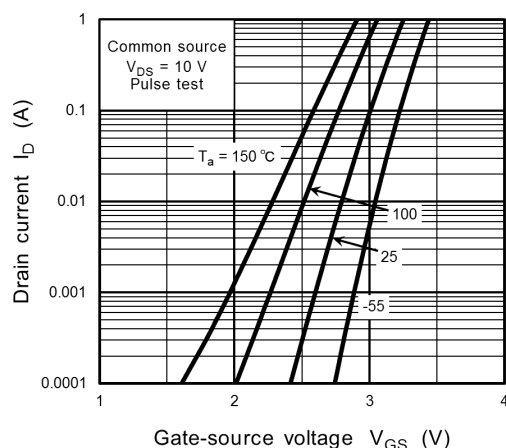


Fig. 8.7  $I_D - V_{GS}$

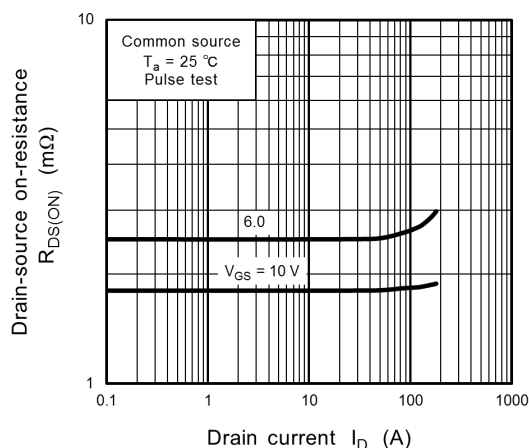


Fig. 8.8  $R_{DS(ON)} - I_D$

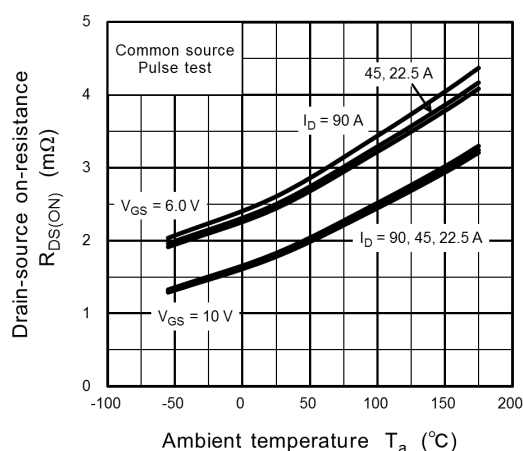


Fig. 8.9  $R_{DS(ON)} - T_a$

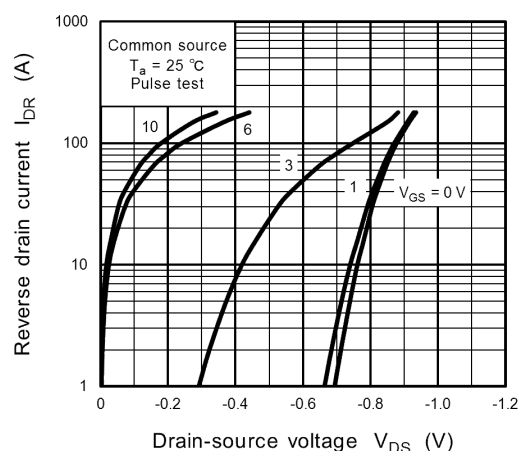


Fig. 8.10  $I_{DR} - V_{DS}$

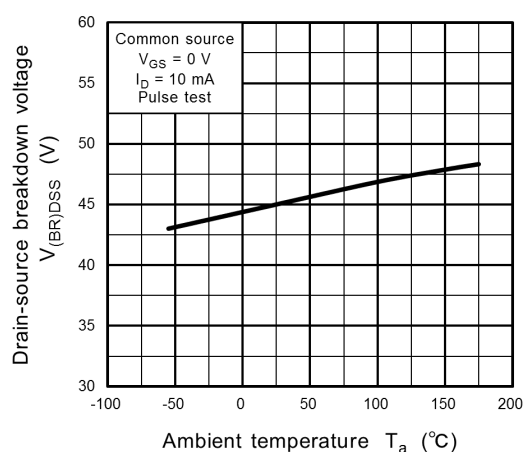


Fig. 8.11  $V_{(BR)DSS} - T_a$

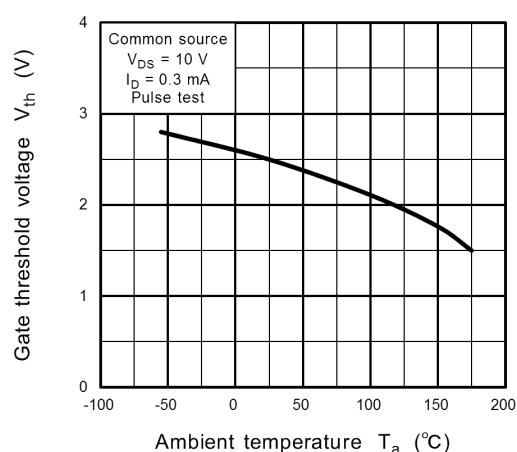


Fig. 8.12  $V_{th} - T_a$

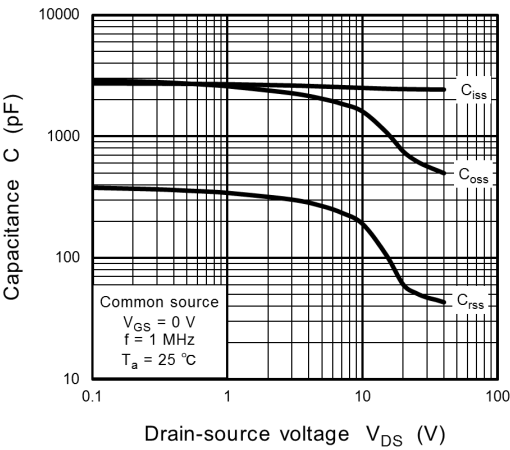


Fig. 8.13 Capacitance -  $V_{DS}$

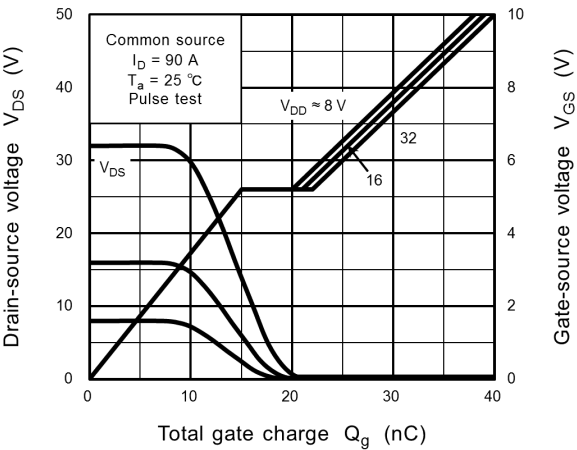


Fig. 8.14 Dynamic Input/Output Characteristics

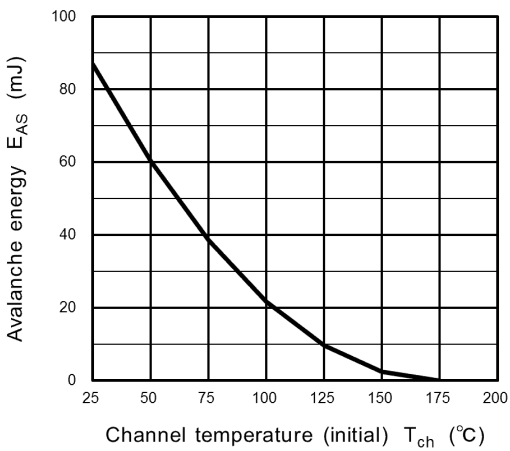


Fig. 8.15  $E_{AS}$  -  $T_{ch}$ (Guaranteed Maximum)

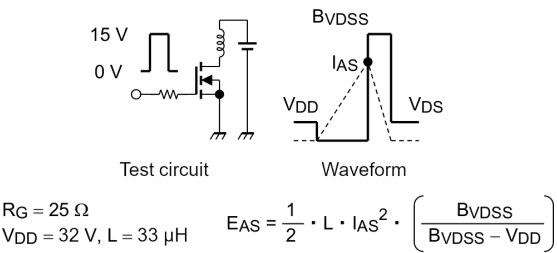


Fig. 8.16 Test Circuit/Waveform

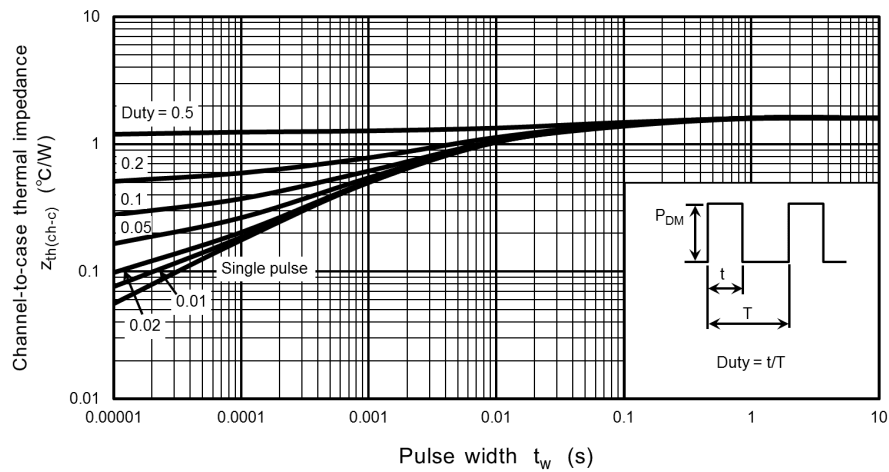


Fig. 8.17  $z_{th(ch-c)} - t_w$   
(Guaranteed Maximum)

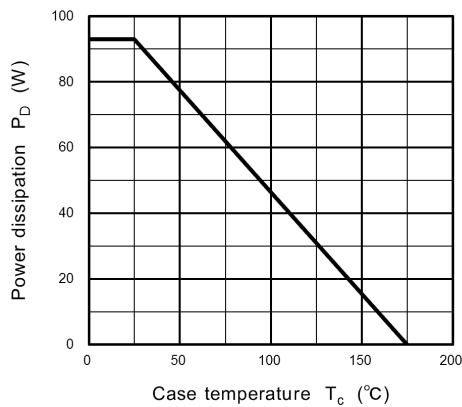


Fig. 8.18  $P_D - T_c$   
(Guaranteed Maximum)

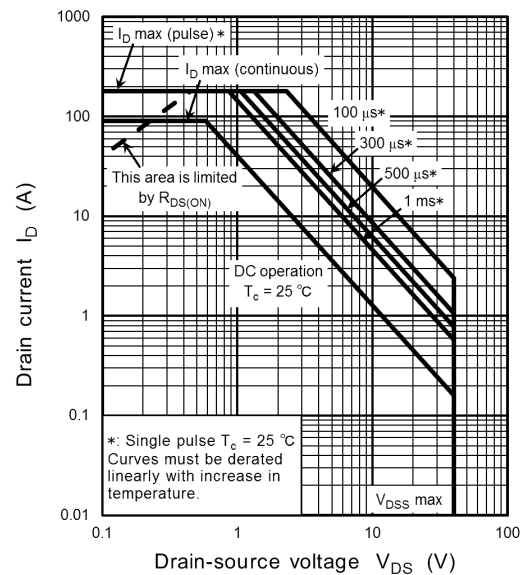


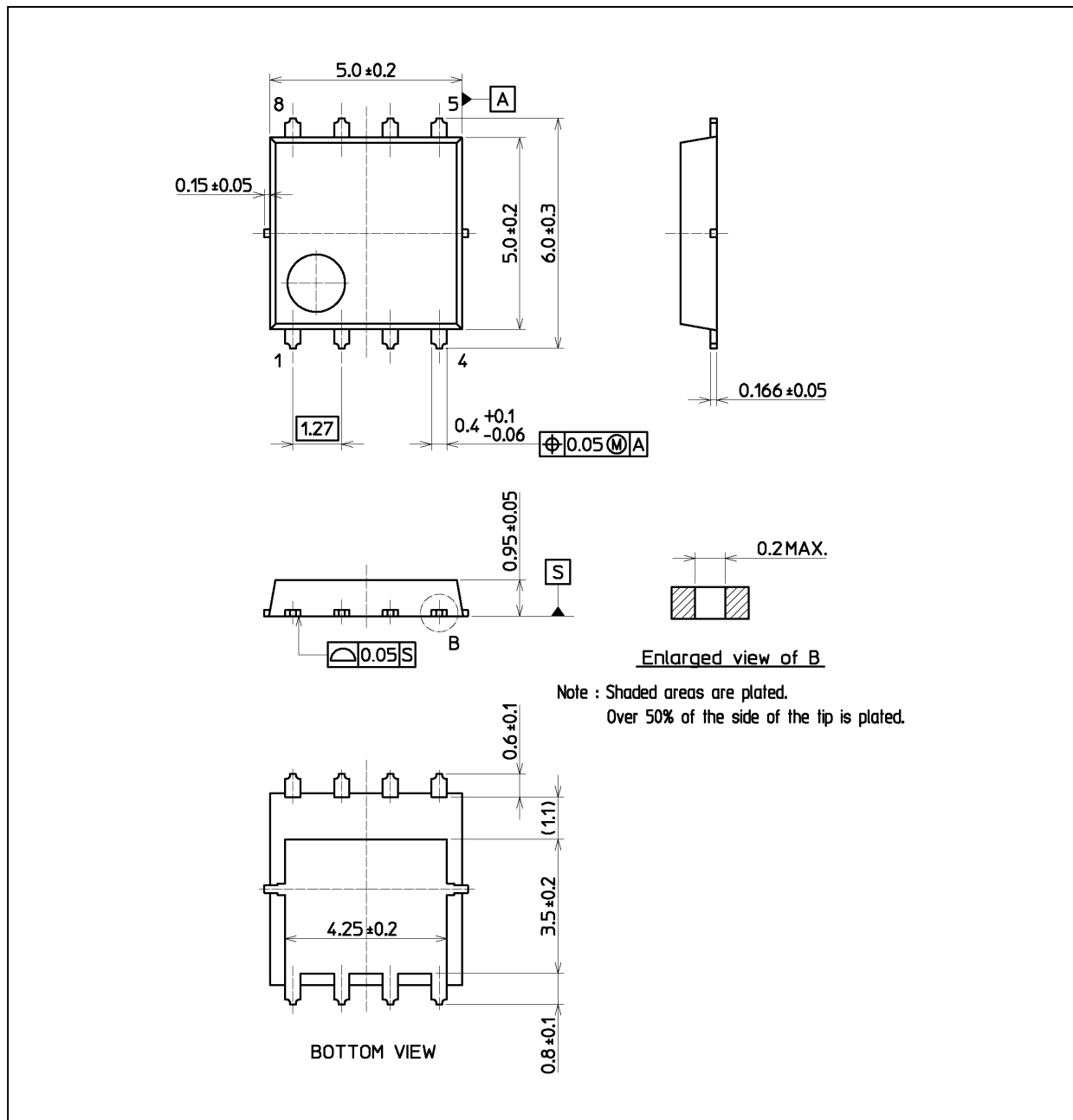
Fig. 8.19 Safe Operating Area  
(Guaranteed Maximum)

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



## Package Dimensions

Unit: mm



Weight: 0.071 g (typ.)

Package Name(s)
TOSHIBA: 2-5Q4A
Nickname: SOP Advance(WF)

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